**Vishay Semiconductors** 

High Performance Schottky Rectifier, 3.0 A



www.vishay.com



SMC (DO-214AB)

PRIMARY CHARACTERISTICS				
I <sub>F(AV)</sub>	3.0 A			
V <sub>R</sub>	60 V			
V <sub>F</sub> at I <sub>F</sub>	0.61 V			
I <sub>RM</sub> max.	30 mA at 125 °C			
T <sub>J</sub> max.	150 °C			
E <sub>AS</sub>	5.0 mJ			
Package	SMC (DO-214AB)			
Circuit configuration	Single			

### **FEATURES**

- · Small foot print, surface mountable
- · Very low forward voltage drop
- High frequency operation



- · Guard ring for enhanced ruggedness and long FREE term reliability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

## **DESCRIPTION / APPLICATIONS**

The VS-MBRS360-M3 surface mount Schottky rectifier has been designed for applications requiring low forward drop and small foot prints on PC boards. Typical applications are in disk drives, switching power supplies, converters, freewheeling diodes, battery charging, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS				
SYMBOL	CHARACTERISTICS	VALUES	UNITS	
I <sub>F(AV)</sub>	Rectangular waveform	3.0	А	
V <sub>RRM</sub>		60	V	
I <sub>FSM</sub>	t <sub>p</sub> = 5 μs sine	790	А	
V <sub>F</sub>	3.0 A <sub>pk</sub> , T <sub>J</sub> = 125 °C	0.61	V	
TJ	Range	-55 to +150	°C	

VOLTAGE RATINGS				
PARAMETER	SYMBOL	VS-MBRS360-M3	UNITS	
Maximum DC reverse voltage	V <sub>R</sub>	60	V	
Maximum working peak reverse voltage	V <sub>RWM</sub>	80	v	

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum average forward current	I	50 % duty cycle at $T_L$ = 118 °C,	rectangular waveform	3.0	
Maximum average forward current	I <sub>F(AV)</sub>	50 % duty cycle at $T_L$ = 105 °C,	rectangular waveform	4.0	
Maximum peak one cycle		5 µs sine or 3 µs rect. pulse	Following any rated load	790	A
non-repetitive surge current	I <sub>FSM</sub>	10 ms sine or 6 ms rect. pulse	condition and with rated V <sub>RRM</sub> applied	80	
Non-repetitive avalanche energy	E <sub>AS</sub>	T <sub>J</sub> = 25 °C, I <sub>AS</sub> = 1.0 A, L = 10 mH		5.0	mJ
Repetitive avalanche current	I <sub>AR</sub>	Current decaying linearly to zero in 1 $\mu s$ Frequency limited by $T_J$ maximum $V_A$ = 1.5 x $V_R$ typical		1.0	А

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ELECTRICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS		TYP.	MAX.	UNITS
		3 A	- T <sub>J</sub> = 25 °C	0.57	0.74	
Maximum forward valtage drep	V <sub>EM</sub> <sup>(1)</sup>	6 A		0.72	0.9	v
Maximum forward voltage drop	VFM ()	3 A	T <sub>J</sub> = 125 °C	0.51	0.61	
		6 A		0.62	0.77	
		T <sub>J</sub> = 25 °C		-	0.5	
Maximum reverse leakage current	I <sub>RM</sub> <sup>(1)</sup>	T <sub>J</sub> = 100 °C	$V_R = Rated V_R$	-	20	mA
		T <sub>J</sub> = 125 °C		-	30	
Maximum junction capacitance	CT	$V_R$ = 5 $V_{DC}$ (test signal range 100 kHz to 1 MHz), 25 °C		-	180	pF
Typical series inductance	L <sub>S</sub>	Measured lead to lead 5 mm from package body -		-	3.0	nH
Maximum voltage rate of change	dV/dt	Rated V <sub>R</sub> - 10 000 V		V/µs		

Note

 $^{(1)}\,$  Pulse width < 300  $\mu s,$  duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction and storage temperature range	$T_{J}$ <sup>(1)</sup> , $T_{Stg}$		-55 to +150	°C
Maximum thermal resistance, junction to lead	R <sub>thJL</sub> <sup>(2)</sup>		12	°C/W
Maximum thermal resistance, junction to ambient	R <sub>thJA</sub>	DC operation	46	
Approximate weight			0.24	g
			0.008	oz.
Marking device		Case style SMC (DO-214AB) 36		6

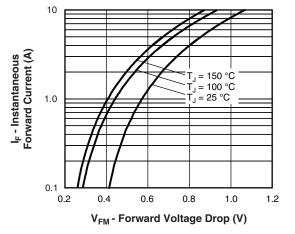
Notes

 $\frac{dP_{tot}}{dT_J} < \frac{1}{R_{thJA}}$  thermal runaway condition for a diode on its own heatsink (1)

<sup>(1)</sup> Mounted 1" square PCB

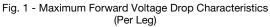


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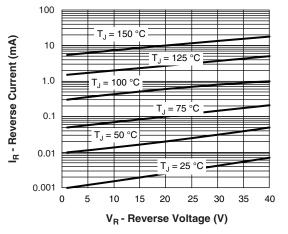


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage (Per Leg)

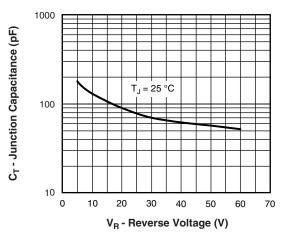
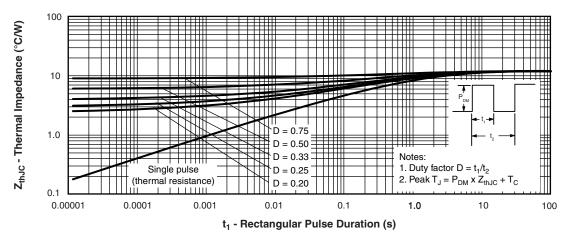


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

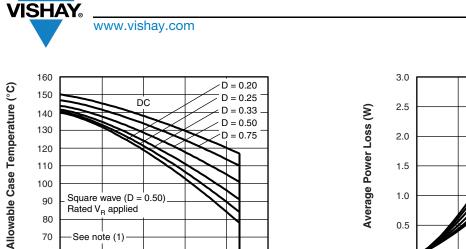




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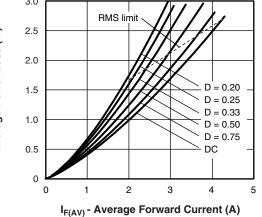
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**VS-MBRS360-M3** 

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Fig. 6 - Maximum Average Forward Dissipation vs. Average Forward Current

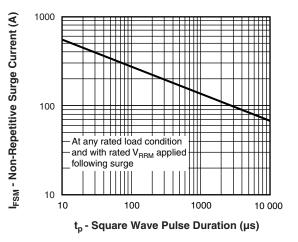


Fig. 7 - Maximum Peak Surge Forward Current vs. Pulse Duration

#### Note

 $\begin{array}{l} \mbox{Formula used: } T_C = T_J \mbox{-} (Pd + Pd_{REV}) \ x \ R_{thJC}; \\ \mbox{Pd} = \mbox{forward power loss} = I_{F(AV)} \ x \ V_{FM} \ at \ (I_{F(AV)}/D) \ (see \ fig. \ 6); \\ \mbox{Pd}_{REV} = \ inverse \ power \ loss = V_{R1} \ x \ I_R \ (1 \ - D); \ I_R \ at \ V_{R1} = 80 \ \% \ rated \ V_R \end{array}$ (1)

80

70

60

0

See note (1)

1

2

I<sub>F(AV)</sub> - Average Forward Current (A) Fig. 5 - Maximum Average Forward Current vs.

Allowable Lead Temperature

3



4 Current rating (3 = 3 A) -

S

(3)

3

(4)

60

(5

Voltage rating (60 = 60 V) -

-M3 = halogen-free, RoHS-compliant, and termination lead (Pb)-free

-M3

6

ORDERING INFORMATION (Example)					
PREFERRED P/N	PREFERRED PACKAGE CODE	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION		
VS-MBRS360-M3/9AT	9AT	3500	13" diameter plastic tape and reel		

LINKS TO RELATED DOCUMENTS			
Dimensions	www.vishay.com/doc?95402		
Part marking information	www.vishay.com/doc?95403		
Packaging information	www.vishay.com/doc?95404		

**Device code** 

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VS-

1

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MBR

(2)

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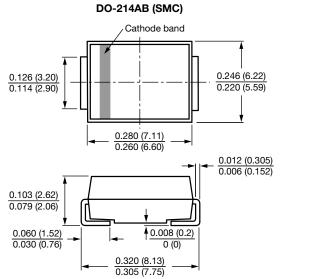


# **Outline Dimensions**

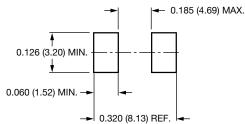
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### **DIMENSIONS** in inches (millimeters)



Mounting Pad Layout





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